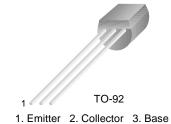


# **BC182L**

# **NPN General Purpose Amplifier**

- This device is designed for general purpose amplifier application at collector currents to 100mA.
- Sourced from process 10.



## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

| Symbol                           | Parameter                          | Value      | Units |
|----------------------------------|------------------------------------|------------|-------|
| V <sub>CEO</sub>                 | Collector-Emitter Voltage          | 50         | V     |
| V <sub>CBO</sub>                 | Collector-Base Voltage             | 60         | V     |
| V <sub>EBO</sub>                 | Emitter-Base Voltage               | 6          | V     |
| I <sub>C</sub>                   | Collector Current - Continuous     | 100        | mA    |
| T <sub>J,</sub> T <sub>STG</sub> | Storage Junction Temperature Range | - 55 ~ 150 | °C    |

## Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

| Symbol                | Parameter                            | Test Condition  | Min.            | Тур. | Max.        | Units |
|-----------------------|--------------------------------------|---|-----------------|------|-------------|-------|
| Off Characteristics   |                                      |   |                 |      |             |       |
| V <sub>(BR)CEO</sub>  | Collector-Emitter Breakdown Voltage  | $I_C = 2mA, I_B = 0$  | 50              |      |             | V     |
| V <sub>(BR)CBO</sub>  | Collector-Base Breakdown Voltage     | $I_C = 10\mu A, I_E = 0$  | 60              |      |             | V     |
| V <sub>(BR)EBO</sub>  | Emitter-Base Breakdown Voltage       | $I_E = 100\mu A, I_C = 0$   | 6               |      |             | V     |
| I <sub>CBO</sub>      | Collector Cut-off Current            | $V_{CB} = 50V, V_{BE} = 0$  |                 |      | 15          | nA    |
| I <sub>EBO</sub>      | Emitter-Base Leakage Current         | $V_{EB} = 4V, I_{E} = 0$  |                 |      | 15          | nA    |
| On Characteristics    |                                      |   |                 |      |             |       |
| h <sub>FE</sub>       | DC Current Gain                      | $V_{CE} = 5V, I_{C} = 10\mu A$ $V_{CE} = 5V, I_{C} = 2mA$ $V_{CE} = 5V, I_{C} = 100mA$        | 40<br>120<br>80 |      | 500         |       |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 10mA, I <sub>B</sub> = 0.5mA<br>I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA |                 |      | 0.25<br>0.6 | V     |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage      | I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA  |                 |      | 1.2         | V     |
| V <sub>BE</sub> (on)  | Base-Emitter On Voltage              | $V_{CE} = 5V$ , $I_C = 2mA$   | 0.55            |      | 0.7         | V     |
| Dynamic (             | Characteristics                      |   |                 |      |             |       |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | $V_{CE} = 5V, I_{C} = 10mA, f = 100MHz$   | 150             |      |             | MHz   |
| C <sub>ob</sub>       | Output Capacitance                   | $V_{CE} = 10V, I_{C} = 0, f = 1MHz$   |                 |      | 5           | pF    |
| h <sub>fe</sub>       | Small Signal Current Gain            | $V_{CE} = 5V$ , $I_C = 2mA$ , $f = 1KHz$  | 240             |      | 500         |       |
| NF                    | Noise Figure                         | $V_{CE} = 5V$ , $I_{C} = 0.2$ mA<br>$R_{S} = 2$ K $\Omega$ , $f = 1$ KHz, BW = 200Hz          |                 |      | 10          | dB    |

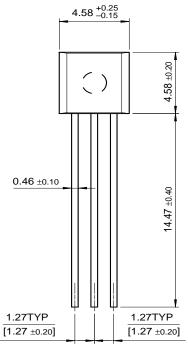
## Thermal Characteristics $T_A=25$ °C unless otherwise noted

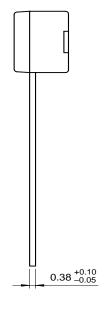
| Symbol          | Parameter                                      | Max. | Units |
|-----------------|--|------|-------|
| P <sub>D</sub>  | Total Device Dissipation @T <sub>A</sub> =25°C |      | mW    |
| _               | Derate above 25°C                              | 2.8  | mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient        | 357  | mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case           | 125  | °C/W  |

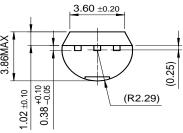
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# **Package Dimensions**

# TO-92







Dimensions in Millimeters

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